NSN 5961-01-395-6123

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-395-6123 **Inclosure Material:** Metal **Overall Length:** 1.513 inches Overall Diameter: 0.544 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.553 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage, peak total value and 600.0 forward voltage, peak **Current Rating Per Characteristic:** 13.50 amperes forward current, total rms universal and 16.00 amperes forward current, total rms nanoamperes and 21.00 amperes forward current, total rms horsepower metric and 300.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector universal and 40.0 watts small-signal input power, common-collector blank and 30.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 97942-588r849 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No